TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7SG04AFS

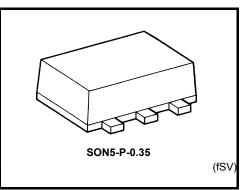
Inverter

#### Features

- High-level output current:  $I_{OH}/I_{OL} = \pm 8$  mA (min) at  $V_{CC} = 3.0$  V
- High-speed operation: t<sub>pd</sub> = 2.3 ns (typ.)

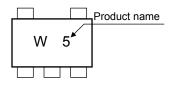
at  $V_{CC} = 3.3 \text{ V},15\text{pF}$ 

- Operating voltage range: V<sub>CC</sub> = 0.9~3.6 V
- 5.5-V tolerant input.

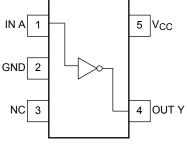


Weight: 0.001 g (typ.)

#### Marking







### Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Value	Unit	
Power supply voltage	V <sub>CC</sub>	-0.5~4.6	V	
DC input voltage	VIN	-0.5~7.0	V	
DC output voltage	V <sub>OUT</sub>	-0.5~ V <sub>CC</sub> + 0.5	V	
Input diode current	IIK	-20	mA	
Output diode current	I <sub>OK</sub>	±20 (Note 1)	mA	
DC output current	IOUT	±25	mA	
DC V <sub>CC</sub> /ground current	ICC	±50	mA	
Power dissipation	PD	50	mW	
Storage temperature	T <sub>stg</sub>	-65~150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

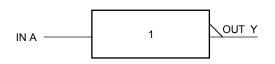
Note 1:  $V_{OUT} < GND$ ,  $V_{OUT} > V_{CC}$ 

# <u>TOSHIBA</u>

## **Truth Table**

А	Y
L	Н
Н	L





# **Operating Ranges**

Characteristics	Symbol	Value	Unit	
Power supply voltage	V <sub>CC</sub>	0.9~3.6	V	
Input voltage	V <sub>IN</sub>	0~5.5	V	
Output voltage	V <sub>OUT</sub>	0~V <sub>CC</sub>	V	
Output Current		±8.0 (Note 2)		
	IOH/IOL	±4.0 (Note 3)		
		±3.0 (Note 4)	mA	
		±1.7 (Note 5)	ШA	
		±0.3 (Note 6)		
		±0.02 (Note 7)		
Operating temperature	T <sub>opr</sub>	-40~85	°C	
Input rise and fall time	dt/dV	0~10 (Note 8)	ns/V	

- Note 2:  $V_{CC} = 3.0 \sim 3.6 \text{ V}$
- Note 3: V<sub>CC</sub> = 2.3~2.7 V
- Note 4:  $V_{CC} = 1.65 \sim 1.95 \text{ V}$
- Note 5:  $V_{CC} = 1.4 \sim 1.6 V$
- Note 6: V<sub>CC</sub> = 1.1~1.3 V
- Note 7:  $V_{CC} = 0.9 V$
- Note 8:  $V_{IN} = 0.8 \text{~} 2.0 \text{ V}, V_{CC} = 3.0 \text{ V}$

# **DC Electrical Characteristics**

Characteristics	cs Symbol Test Condition		_	Ta = 25°C			Ta = -40~85°C		Unit	
		1631	V <sub>CC</sub>		Min	Тур.	Max	Min	Max	Unit
High-level VIH input voltage				V <sub>CC</sub>	_		V <sub>CC</sub>		V	
	—		1.1~1.3	$\begin{array}{c} V_{CC} \\ \times \ 0.7 \end{array}$		—	V <sub>CC</sub> × 0.7	_		
			1.4~1.6	V <sub>CC</sub> × 0.65		—	V <sub>CC</sub> × 0.65	_		
			1.65~1.95	V <sub>CC</sub> × 0.65		_	V <sub>CC</sub> × 0.65			
					1.7		—	1.7	_	
				3.0~3.6	2.0		_	2.0	_	
							GND		GND	
Low-level V <sub>IL</sub> input voltage			1.1~1.3	_	_	$V_{CC} \times 0.3$	—	$\begin{array}{c} V_{CC} \\ \times \ 0.3 \end{array}$		
				_	_	$\begin{array}{c} V_{CC} \\ \times \ 0.35 \end{array}$	—	$\begin{array}{c} V_{CC} \\ \times \ 0.35 \end{array}$	V	
						$\begin{array}{c} V_{CC} \\ \times \ 0.35 \end{array}$	—	$\begin{array}{c} V_{CC} \\ \times \ 0.35 \end{array}$		
				_	_	0.7		0.7		
			3.0~3.6	—	_	0.8		0.8		
			I <sub>OH</sub> =-0.02 mA	0.9	0.75		_	0.75	—	V
		V <sub>IN</sub> = V <sub>IL</sub>	I <sub>OH</sub> = -0.3 mA	1.1~1.3	$\begin{array}{c} V_{CC} \\ \times \ 0.75 \end{array}$		_	$\begin{array}{c} V_{CC} \\ \times \ 0.75 \end{array}$		
High-level	V <sub>ОН</sub>		I <sub>OH</sub> = -1.7 mA	1.4~1.6	V <sub>CC</sub> × 0.75	_	_	V <sub>CC</sub> × 0.75	_	
output voltage		I <sub>OH</sub> = -3.0 mA	1.65~ 1.95	V <sub>CC</sub> -0.45		_	V <sub>CC</sub> -0.45			
			I <sub>OH</sub> = -4.0 mA	2.3~2.7	2.0			2.0		
			I <sub>OH</sub> = -8.0 mA	3.0~3.6	2.48	_	_	2.48	_	
			$I_{OL} = 0.02 \text{ mA}$	0.9			0.1		0.1	
Low-level V <sub>OL</sub> V <sub>IN</sub> output voltage		I <sub>OL</sub> = 0.3 mA	1.1~1.3			V <sub>CC</sub> × 0.25	_	V <sub>CC</sub> × 0.25		
	Vol	$V_{IN} = V_{IH}$	I <sub>OL</sub> = 1.7 mA	1.4~1.6	_	_	V <sub>CC</sub> × 0.25	_	V <sub>CC</sub> × 0.25	25 V
			I <sub>OL</sub> = 3.0 mA	1.65~ 1.95			0.45		0.45	
			I <sub>OL</sub> = 4.0 mA	2.3~2.7			0.4		0.4	
			I <sub>OL</sub> = 8.0 mA	3.0~3.6	_	_	0.4		0.4	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 0~5.5V		0~3.6			±0.1		±1.0	μA
Quiescent supply current	Icc	$V_{IN} = V_{CC}$ or GND		3.6	_	_	1.0	_	10.0	μA

## AC Electrical Characteristics (input $t_r = t_f = 3 \text{ ns}$ )

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = −40~85°C		Unit
Characteristics			V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Unit
		$C_L = 10 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	0.9	_	18.6		_	_	
			1.1~1.3	_	8.7	18.4	1.0	34.2	
			1.4~1.6	_	4.9	8.5	1.0	10.0	
			1.65~ 1.95		3.8	6.2	1.0	6.7	
			2.3~2.7	_	2.6	3.9	1.0	4.4	
			3.0~3.6	_	2.1	3.1	1.0	3.7	
			0.9	_	21.0			_	
	tрLH tpнL	C <sub>L</sub> = 15 pF, R <sub>L</sub> = 1 MΩ	1.1~1.3	_	9.8	21.5	1.0	37.1	ns
			1.4~1.6	_	5.4	9.3	1.0	11.2	
Propagation delay time			1.65~ 1.95		4.2	6.9	1.0	7.1	
			2.3~2.7	_	2.8	4.4	1.0	5.0	
			3.0~3.6		2.3	3.4	1.0	3.9	-
		$C_L = 30 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	0.9	_	31.2	_	_	_	
			1.1~1.3		13.8	29.6	1.0	56.0	
			1.4~1.6		7.4	13.1	1.0	15.9	
			1.65~ 1.95	_	5.6	9.2	1.0	9.6	
			2.3~2.7	_	3.7	5.7	1.0	6.1	
			3.0~3.6		2.9	4.4	1.0	4.8	
Input capacitance	C <sub>IN</sub>	—	3.6	_	3	_		—	pF
Power dissipation capacitance	C <sub>PD</sub>	(Note9)	0.9~3.6		6		_	_	pF

Note 9: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

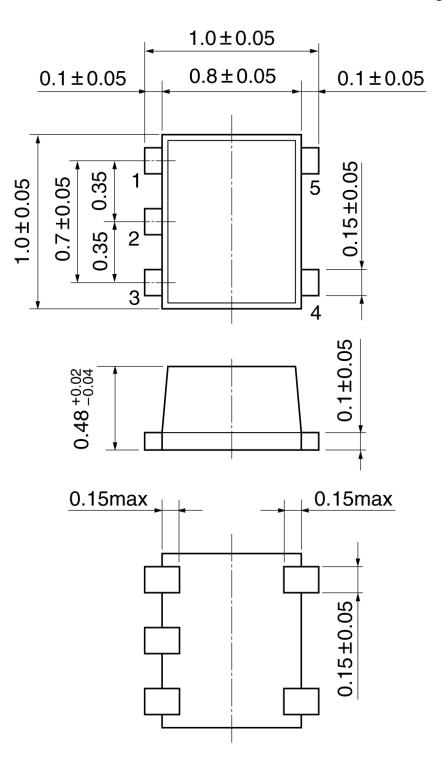
 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 

# **TOSHIBA**

# Package Dimensions

SON5-P-0.35

Unit:mm



Weight: 0.001 g (typ.)

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20070701-EN GENERAL

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